

November 1999

## FDS6890A

## Dual N-Channel 2.5V Specified PowerTrench™ MOSFET

#### **General Description**

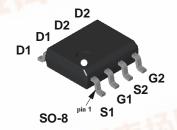
These N-Channel 2.5V specified MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance.

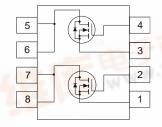
## **Applications**

- DC/DC converter
- Motor drives

#### **Features**

- 7.5 A, 20 V.  $R_{DS(ON)} = 0.018~\Omega~$  @  $V_{GS} = 4.5~V$   $R_{DS(ON)} = 0.022~\Omega~$  @  $V_{GS} = 2.5~V.$
- Low gate charge (23nC typical).
- Fast switching speed.
- High performance trench technology for extremely low R<sub>DS(ON)</sub>.
- High power and current handling capability.





Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage		20	V
V <sub>GSS</sub>	Gate-Source Voltage		±8	V
I <sub>D</sub>	Drain Current - Continuous	(Note 1a)	7.5	А
	- Pulsed		20	- TUD
P <sub>D</sub>	Power Dissipation for Dual Operation		2.0	W
	Power Dissipation for Single Operation	(Note 1a)	1.6	Dr
		(Note 1b)	1.0	
		(Note 1c)	0.9	
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperat	ure Range	-55 to +150	°C

#### Thermal Characteristics

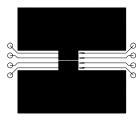
R <sub>e</sub> JA	Thermal Resistance, Junction-to-Ambient	(Note 1a)	78	°C/W
R <sub>e</sub> JC	Thermal Resistance, Junction-to-Case	(Note 1)	40	°C/W
			90	

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape Width	Quantity
FDS6890A	FDS6890A	13	12mm	2500 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chai	acteristics					•
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	20			V
<u>ΔBVɒss</u> ΔTJ	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu A$ , Referenced to $25^{\circ}C$		14		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 16 V, V <sub>GS</sub> = 0 V			1	μΑ
I <sub>GSSF</sub>	Gate-Body Leakage Current, Forward	V <sub>GS</sub> = 8 V, V <sub>DS</sub> = 0 V			100	nA
I <sub>GSSR</sub>	Gate-Body Leakage Current, Reverse	$V_{GS} = -8 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.5	0.8	1.5	V
$\Delta V_{GS(th)} \over \Delta T_J$	Gate Threshold Voltage Temperature Coefficient	$I_D$ = 250 $\mu$ A, Referenced to 25°C		-3.5		mV/°C
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance	$\begin{array}{c} V_{GS} = 4.5 \text{ V}, I_D = 7.5 \text{ A} \\ V_{GS} = 4.5 \text{ V}, I_D = 7.5 \text{ A}, T_J = 125^{\circ}\text{C} \\ V_{GS} = 2.5 \text{ V}, I_D = 6.5 \text{ A} \end{array}$		0.013 0.021 0.016	0.018 0.034 0.022	Ω
I <sub>D(on)</sub>	On-State Drain Current	V <sub>GS</sub> = 10 V, V <sub>DS</sub> = 5 V	20			Α
<b>g</b> FS	Forward Transconductance	V <sub>DS</sub> = 5 V, I <sub>D</sub> = 7.5 A		35		S
Dvnamio	Characteristics					
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$		2130		pF
Coss	Output Capacitance	f = 1.0 MHz		545		pF
Crss	Reverse Transfer Capacitance			270		pF
Switchir	ng Characteristics (Note 2)					
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>DD</sub> = 10 V, I <sub>D</sub> = 1 A,		13	24	ns
t <sub>r</sub>	Turn-On Rise Time	$V_{GS} = 4.5 \text{ V}, R_{GEN} = 6 \Omega$		26	42	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	1		65	90	ns
t <sub>f</sub>	Turn-Off Fall Time	7		23	37	ns
Qg	Total Gate Charge	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 7.5 A,		23	32	nC
Q <sub>gs</sub>	Gate-Source Charge	$V_{GS} = 4.5 \text{ V},$		3.2		nC
$Q_{gd}$	Gate-Drain Charge			4.4		nC
Drain-So	ource Diode Characteristics	and Maximum Ratings				
Is	Maximum Continuous Drain-Source				1.3	Α
V <sub>SD</sub>	Drain-Source Diode Forward	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 1.3 A (Note 2)		0.65	1.2	V

 $\textbf{1.} \ \ R_{\theta JA} \ \text{is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting}$ surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.





a) 78° C/W when mounted on a 0.5 in² pad of 2 oz. copper.

b) 125° C/W when mounted on a 0.02 in² pad of 2 oz. copper.

c) 135° C/W when mounted on a mounted on a minimum pad.



Scale 1 : 1 on letter size paper

## Typical Characteristics (continued)

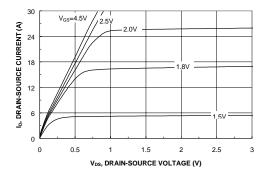


Figure 1. On-Region Characteristics.

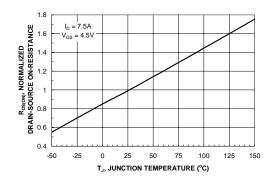


Figure 3. On-Resistance Variation with Temperature.

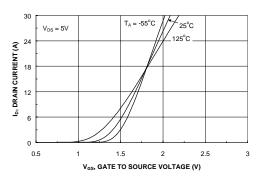


Figure 5. Transfer Characteristics.

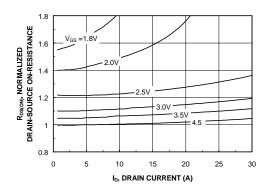


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

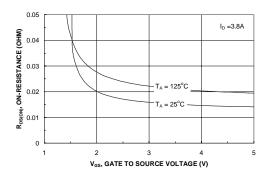


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

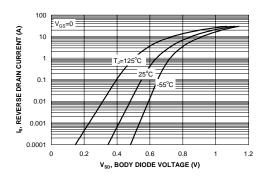
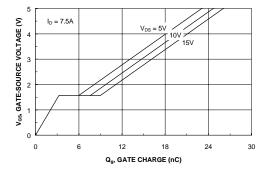


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

## Typical Characteristics (continued)



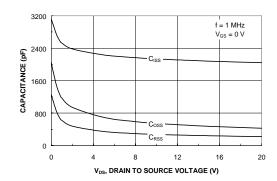
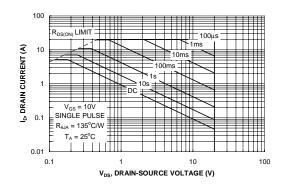


Figure 7. Gate Charge Characteristics.





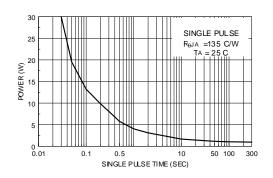


Figure 9. Maximum Safe Operating Area.

Figure 10. Single Pulse Maximum Power Dissipation.

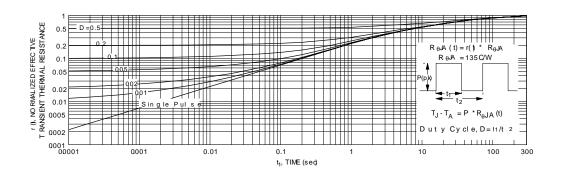
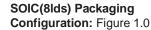


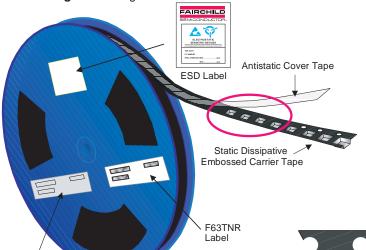
Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1c. Transient themal response will change depending on the circuit board design.

## SO-8 Tape and Reel Data and Package Dimensions



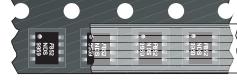




#### Packaging Description:

SOIC-8 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 2,500 units per 13° or 330m diameter reel. The reels are dark blue in color and is made of polystyrene plastic (anti-static coated). Other option comes in 500 units per 7° or 177cm diameter reel. This and some other options are further described in the Packaging Information table.

These full reels are individually barcode labeled and placed inside a standard intermediate box (illustrated in figure 1.0) made of recyclable corrugated brown paper. One box contains two reels maximum. And these boxes are placed inside a barcode labeled shipping box which comes in different sizes depending on the number of parts





Packaging Option no flow code) Packaging type Rail/Tube TNR TNR Qty per Reel/Tube/Bag 2,500 95 4,000 500 Reel Size 13" Dia 13" Dia 7" Dia Box Dimension (mm) 343x64x343 530x130x83 343x64x343 184x187x47 Max qty per Box 5,000 30,000 8,000 1,000

SOIC (8lds) Packaging Information

Weight per unit (gm) 0.0774 0.0774 0.0774 0.0774 Weight per Reel (kg) 0.6060 0.9696 0.1182 Note/Comments

**SOIC-8 Unit Orientation** 

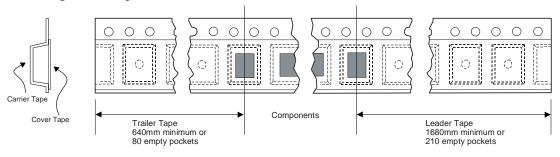
#### F63TNR Label sample

Customized



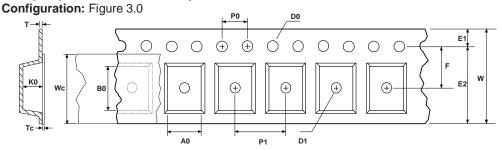
# 343mm x 342mm x 64mm Standard Intermediate box ESD Label F63TN Label

#### SOIC(8lds) Tape Leader and Trailer Configuration: Figure 2.0



## SO-8 Tape and Reel Data and Package Dimensions, continued

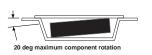
## SOIC(8lds) Embossed Carrier Tape



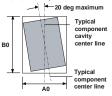
User Direction of Feed	
	$\overline{}$

Dimensions are in millimeter														
Pkg type	Α0	В0	w	D0	D1	E1	E2	F	P1	P0	K0	Т	Wc	Тс
SOIC(8lds) (12mm)	6.50 +/-0.10	5.30 +/-0.10	12.0 +/-0.3	1.55 +/-0.05	1.60 +/-0.10	1.75 +/-0.10	10.25 min	5.50 +/-0.05	8.0 +/-0.1	4.0 +/-0.1	2.1 +/-0.10	0.450 +/- 0.150	9.2 +/-0.3	0.06 +/-0.02

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation



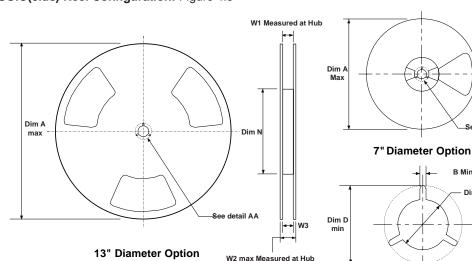
Sketch B (Top View)
Component Rotation



Sketch C (Top View)

Component lateral movement

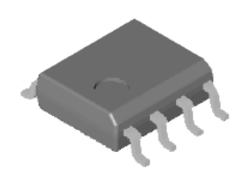
### SOIC(8lds) Reel Configuration: Figure 4.0

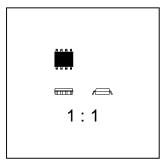


								DETAIL AA	1
Dimensions are in inches and millimeters									
Tape Size	Reel Option	Dim A	Dim B	Dim C	Dim D	Dim N	Dim W1	Dim W2	Dim W3 (LSL-USL)
12mm	7" Dia	7.00 177.8	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	2.165 55	0.488 +0.078/-0.000 12.4 +2/0	0.724 18.4	0.469 - 0.606 11.9 - 15.4
12mm	13" Dia	13.00 330	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	7.00 178	0.488 +0.078/-0.000 12.4 +2/0	0.724 18.4	0.469 - 0.606 11.9 - 15.4

## SO-8 Tape and Reel Data and Package Dimensions, continued

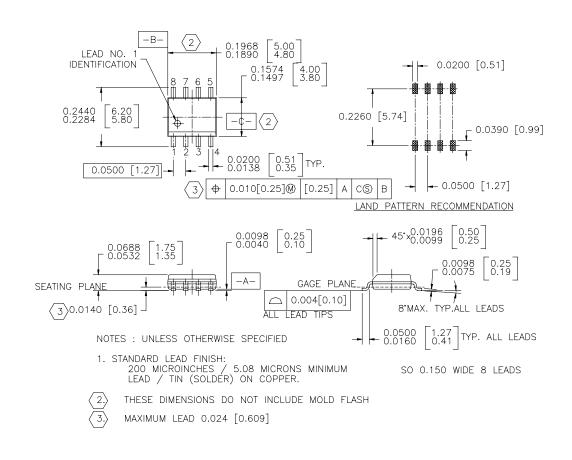
## SOIC-8 (FS PKG Code S1)





Scale 1:1 on letter size paper
Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.0774



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UHC™ VCX™

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